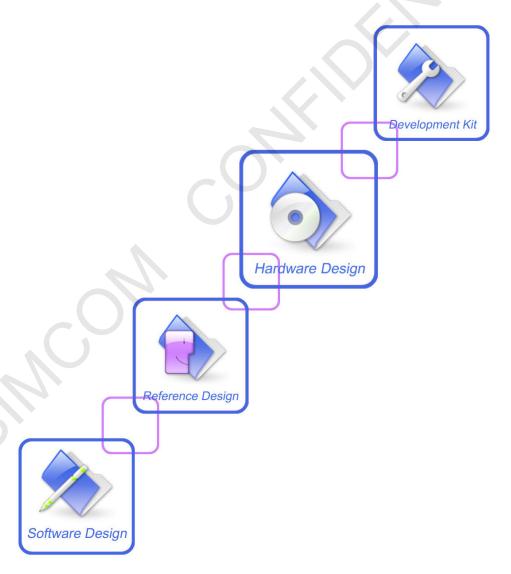


SIM7500A_SIM7500E_SIM7500JE_ SIM7500JC_SIM7500S_SIM7500SA _Hardware Design_V1.02





Document Title	SIM7500A_SIM7500E_SIM7500JE_SIM7500JC_SIM7500S_ SIM7500SA Hardware Design		
Version	V1.02		
Date	2017-01-03		
Status	Released		
Document Control ID	SIM7500A_SIM7500E_SIM7500JE_SIM7500JC_SIM7500S_ SIM7500SA_Hardware Design_V1.02		

General Notes

SIMCom offers this information as a service to its customers to support the application and engineering efforts that use the products designed by SIMCom. The information provided is based on the requirements specifically from the customers. SIMCom has not undertaken any independent search for additional relevant information, including any information that may be in the customer's possession. Furthermore, the system validation of the product designed by SIMCom within a larger electronic system remains the responsibility of the customer or the customer's system integrator. All specifications supplied herein are subject to change without notice.

Copyright

This document contains the proprietary technical information which is the property of SIMCom Limited, copying of this document, giving it to others, the using or communication of the contents thereof are forbidden without the official authority by SIMCom. Offenders are liable to the payment of the damages. All rights are reserved in the event of grant of a patent or the registration of a utility model or design. All specifications supplied herein are subject to change without notice

Copyright © SIMCom Wireless Solutions Co., Ltd. 2016



Contents

Conte	ents	3
Table	Index	5
Figur	e Index	6
	ion History	
	-	
	ntroductionProduct Outline	8
1.1		
1.2	Hardware Interface Overview	
1.3	Hardware Block Diagram	
1.4		
2 P	ackage Information	
2.1	Pin Assignment Overview	
2.2	Pin Description	
2.3	Mechanical Information	
2.4	Footprint Recommendation	
3 Ir	nterface Application	17
3.1	Power Supply	
3.	1.1 Power supply Design Guide	
3.	1.2 Recommended Power Supply Circuit	
3.	1.3 Voltage Monitor	19
3.2	Power on/Power off/Reset Function	19
3.	2.1 Power on	19
3.	2.2 Power off	20
3.	2.3 Reset Function	22
3.3	UART Interface	22
3.	3.1 UART Design Guide	23
3.	3.2 RI and DTR Behavior	24
3.4	USB Interface	25
3.	4.1 USB Application Guide	25
3.5	SIM Interface	25
3.	5.1 SIM Application Guide	26
3.	5.2 SIM Card Design Guide	27
3.	5.3 Recommended SIM Card Holder	28
3.6	PCM Interface	28
3.	6.1 PCM Timing	29
3.	6.2 PCM Application Guide	30
3.7	I2C Interface	31
3.	7.1 I2C Design Guide	31
3.8	Network Status	31
3.9	Operating Status Indication	32



Smart Machine Smart Decision

				me smart B telsion
	3.10]	Flight Mode Control	32
	3.11]	Pin Multiplex Function	33
	3.12	(Other interface	33
	3.1	12.1	Sink Current Source	33
	3.1	12.2	ADC	34
4	RI	F Sp	ecifications	35
	4.1	-	CDMA/LTE RF Specifications	
	4.2	GS	SM/WCDMA/LTE Antenna Design Guide	37
	4.3	Gì	NSS	38
	4.3	3.1	GNSS Technical specification	38
	4.3	3.2	GNSS Application Guide	39
5	El	ectri	cal Specifications	41
Ĭ	5.1		solute Maximum Ratings	
	5.2		perating Conditions	
	5.3		perating Mode	
	5.3	_	Operating Mode Definition	
	5.3	3.2	Sleep Mode	
	5.3	3.3	Minimum Functionality Mode and Flight Mode	
	5.4	Cu	rrent Consumption	43
	5.5	ES	D Notes	45
6	SN	ит і	Production Guide	46
Ī	6.1		p and Bottom View of Module	
	6.2		bel Information	
	6.3		pical SMT Reflow Profile	
	6.4	-	Disture Sensitivity Level (MSL)	
	6.5	Ste	encil Foil Design Recommendation	49
7	Ρa	cka	zing	50
A			~ ·	
			ence Design	
			g Schemes and Maximum Net Data Rates over Air Interface	
			d Documents	
			and Abbreviations	
	E. Sa	atety	Caution	59



Table Index

Table 1: SIM7500 series frequency bands	8
Table 2: General features	9
Table 3: Pin Definitions	12
Table 4: IO parameters definition	13
Table 5: Pin description	13
Table 6: VBAT Pins electronic characteristic	17
Table 7: Recommended zener diode list	18
Table 8: Power on timing and electronic characteristic	20
Table 9: Power off timing and Electronic Characteristic	21
Table 10: RESET pin electronic characteristic	
Table 11: SIM Electronic characteristic in 1.8V mode (SIM_VDD=1.8V)	25
Table 12: SIM Electronic characteristic 3.0V mode (SIM_VDD=2.95V)	26
Table 13: Amphenol SIM Socket Pin Description	
Table 14: PCM Format	28
Table 15: PCM Timing Parameters	29
Table 16: NETLIGHT pin status	32
Table 17: Pin definition of the STATUS	
Table 18: FLIGHTMODE Pin Status	33
Table 19: Pin multiplex function list	33
Table 20: Sink current electronic characteristic	33
Table 21: ADC Electronic Characteristics	34
Table 22: Conducted transmission power	35
Table 23: Operating frequencies	35
Table 24: Conducted receive sensitivity	36
Table 25: Reference sensitivity (QPSK)	36
Table 26: Trace Loss	37
Table 27: Recommended TVS	38
Table 28: LNA requirements	40
Table 29: Absolute maximum ratings	41
Table 30: Recommended operating ratings	41
Table 31: 1.8V Digital I/O characteristics*	41
Table 32: Operating temperature	42
Table 33: Operating mode Definitions	42
Table 34: Current consumption on VBAT Pins (VBAT=3.8V)	44
Table 35: The ESD performance measurement table (Temperature: 25 °C, Humidity: 45%)	45
Table 36: The Description of Label Information	47
Table 37: Moisture Sensitivity Level and Floor Life	48
Table 38: Tray size	50
Table 39: Small Carton size	51
Table 40: Big carton size	51
Table 41: Coding schemes and maximum net data rates over air interface	
Table 42: Related documents	55
Table 43: Terms and Abbreviations	57



Figure Index

Figure 1: SIM7500 series Block Diagram	9
Figure 2: Pin assignment overview	11
Figure 3: Dimensions (Unit: mm)	15
Figure 4: Footprint recommendation (Unit: mm)	16
Figure 5: Power supply application circuit	17
Figure 6: Linear regulator reference circuit	
Figure 7: Switching mode power supply reference circuit	18
Figure 8: Reference Power on/off Circuit	19
Figure 9: Power on timing sequence	
Figure 10: Power off timing sequence	21
Figure 11: Reference reset circuit	
Figure 12: UART full modem	
Figure 13: UART null Modem	23
Figure 14: Reference circuit of level shift	
Figure 15: RI behaviour (SMS and URC report)	
Figure 16: RI behaviour (voice call)	
Figure 17: USB reference circuit	25
Figure 18: Reference circuit of the 8-pin SIM card holder	26
Figure 19: SIM interface reference circuit	
Figure 20: Amphenol SIM card socket	
Figure 21: PCM_SYNC timing	29
Figure 22: EXT codec to module timing	
Figure 23: Module to EXT codec timing	29
Figure 24: Audio codec reference circuit	
Figure 25: I2C reference circuit	31
Figure 26: NETLIGHT reference circuit	32
Figure 27: Flight Mode Switch Reference Circuit	
Figure 28: ISINK reference circuit.	34
Figure 29: Antenna matching circuit (MAIN_ANT)	37
Figure 30: Antenna matching circuit (DIV_ANT)	38
Figure 31: Active antenna circuit	39
Figure 32: Passive antenna circuit (Default)	39
Figure 33: Top and bottom view of Module	46
Figure 34: Label Information	47
Figure 35: The ramp-soak-spike Reflow Profile of Module	48
Figure 36: Packaging introduce	50
Figure 37: Module tray drawing introduce	50
Figure 38: Small carton drawing introduce	51
Figure 39: Big carton drawing introduce	
Figure 40: Reference design	52



Revision History

Data	Version	Description of change	Author
2016-07-06	1.00	Original	Yuan Shijie Teng lili
2016-11-01	1.01	Modify Document name Add SIM7500JC/SIM7500S/SIM7500SA/SIM7500E project Modify GPIO_49 to FlightMode Modify VBUS Minimum Voltage from 3.6V to 3.0V Modify figure 18, figure 23 and figure 39. Modify Table 8, table 9 figure 18 and figure 23.	Shengwu.sun Shijie.yuan LiLi.teng
2017-01-03	1.02	Modify figure 8, figure 11. Add SIM Card reference circuit with hot plug in	Shengwu.sun Shijie.yuan



1 Introduction

This document describes the electronic specifications, RF specifications, interfaces, mechanical characteristics and testing results of the SIMCom SIM7500 series. With the help of this document and other software application notes/user guides, users can understand and use modules to design and develop applications quickly.

1.1 Product Outline

The SIM7500 series support many air-interface standards, refer to the following table.

Table 1: SIM7500 series frequency bands

64	E	SIM7500A	SIM7500E	CIMIZEONIE	SIM7500JC	CIMTEOOC	CIMTEOOCA
Standard	Frequency	S1W1/500A		SIM7500JE	SIM1/SUUJC	SIM7500S	SIM7500SA
GSM	900MHz		✓				
	1800M Hz		✓				
	BAND1						✓
WCDMA	BAND2	✓					
	BAND5	✓					✓
	LTE-FDD B1			✓	✓		✓
	LTE-FDD B2	✓					
	LTE-FDD B3		1	✓			✓
	LTE-FDD B4	✓					
	LTE-FDD B5						✓
	LTE-FDD B7		✓				✓
LTE	LTE-FDD B8			✓			✓
LIE	LTE-FDD B12	✓				✓	
	LTE-FDD B18				✓		
	LTE-FDD B19				✓		
	LTE-FDD B20		✓				
	LTE-FDD B25					✓	
	LTE-FDD B26				✓	✓	
	LTE-FDD B28						✓
Category		CAT1	CAT1	CAT1	CAT1	CAT1	CAT1
GNSS	7		✓	✓	✓	✓	✓

With a small physical dimension of 24*27*2.75 mm and with the functions integrated, the Module can meet almost any space requirement in users' applications, such as smart phones, PDA's, industrial handhelds, machine-to-machine, vehicle applications, etc.



1.2 Hardware Interface Overview

The interfaces that are described in detail in the next chapters include:

- Power Supply
- USB Interface
- UART Interface
- SIM Interface
- GPIO
- ADC
- Power Output
- Current Sink Source
- PCM Interface
- I2C Interface

1.3 Hardware Block Diagram

The block diagram of the Module is shown in the figure below.

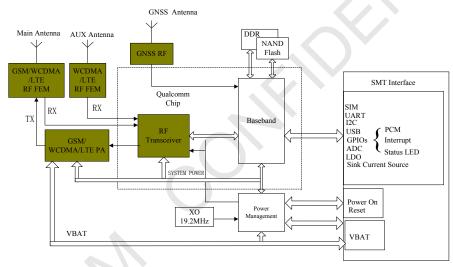


Figure 1: SIM7500 series Block Diagram

1.4 Functional Overview

Table 2: General features

Feature	Implementation
Power supply	Single supply voltage 3.4~4.2V
Power saving	Current in sleep mode : <5mA
Radio frequency bands	Please refer to the table 1
Transmitting power	GSM/GPRS: Class 4 (2W): EGSM900



A company of SIM Tech	Smart Machine Smart Decision			
	Class 1 (1W): DCS1800			
	EDGE:			
	Class E2 (0.5W): EGSM900			
	Class E1 (0.4W): DCS1800			
	WCDMA: Class 3 (0.25W)			
	LTE: Class 3 (0.25W)			
	GPRS multi-slot class 12			
Data Transmission	EDGE multi-slot class 12UMTS R99 speed: 384 kbps DL/UL			
Throughout	HSPA+: 5.76 Mbps(UL), 42 Mbps(DL)			
	LTE Category 1: 10 Mbps (DL)			
	LTE Category 1: 5 Mbps (UL)			
	GSM/WCDMA /LTE main antenna			
Antenna	WCDMA /LTE auxiliary antenna			
	GNSS antenna			
	GNSS engine (GPS,GLONASS and BD)			
GNSS	Protocol: NMEA			
	MT, MO, CB, Text and PDU mode			
SMS	SMS storage: SIM card or ME(default)			
SIVIS				
	Transmission of SMS alternatively over CS or PS.			
SIM interface	Support identity card: 1.8V/3V			
SIM application toolkit	Support SAT class 3, GSM 11.14 Release 98			
Shvi application toolkit	Support USAT			
Phonebook management	Support phonebook types: DC,MC,RC,SM,ME,FD,ON,LD,EN			
	Support PCM interface			
Audio feature	Only support PCM master mode and short frame sync, 16-bit linear data			
	formats			
	A full modem serial port by default			
	Baud rate: 300bps to 4Mbps(default:115200bps)			
	Auto-bauding baud rate: 9600,19200,38400,57600,115200bps			
UART interface	Can be used as the AT commands or data stream channel.			
	Support RTS/CTS hardware handshake			
	Multiplex ability according to GSM 07.10 Multiplexer Protocol.			
Lian				
USB	USB 2.0 specification-compliant as a peripheral			
Firmware upgrade USB	Firmware upgrade over USB interface			
10 522	USB 2.0 specification-compliant as a peripheral			
Physical characteristics	Weight: 4.0 g Size: 24*27*2.75mm			
	Normal operation temperature: -30°C to +80°C			
Temperature range	Extended operation temperature: -40°C to +85°C*			
	Storage temperature -45°C to +90°C			

*Note: Module is able to make and receive voice calls, data calls, SMS and make WCDMA/HSPA+/LTE traffic in -40°C \sim +85°C. The performance will be reduced slightly from the 3GPP specifications if the temperature is outside the normal operating temperature range and still within the extreme operating temperature range.



2 Package Information

2.1 Pin Assignment Overview

All functions of the SIM7500 series will be provided through 56 pads that will be connected to the customers' platform. The following Figure is a high-level view of the pin assignment of the SIM7500 series.

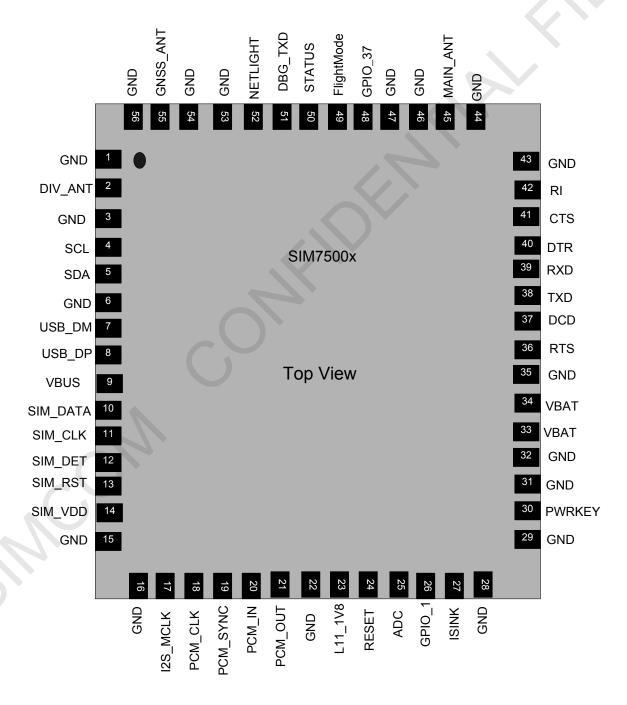


Figure 2: Pin assignment overview SIM7500A_SIM7500E_SIM7500JE_SIM7500JC_SIM7500S_SIM7500SA_Hardware Design_V1.02 2017-01-03



Table 3: Pin Definitions

Pin No.	Pin Name	Pin No.	Pin Name
1	GND	2	DIV_ANT
3	GND	4	SCL
5	SDA	6	GND
7	USB_DM	8	USB_DP
9	VBUS	10	SIM_DATA
11	SIM_CLK	12	SIM_DET
13	SIM_RST	14	SIM_VDD
15	GND	16	GND
17	I2S_MCLK	18	PCM_CLK
19	PCM_SYNC	20	PCM_IN
21	PCM_OUT	22	GND
23	L11_1V8	24	RESET
25	ADC	26	GPIO_1
27	ISINK	28	GND
29	GND	30	PWRKEY
31	GND	32	GND
33	VBAT	34	VBAT
35	GND	36	RTS
37	DCD	38	TXD
39	RXD	40	DTR
41	CTS	42	RI
43	GND	44	GND
45	MAIN_ANT	46	GND
47	GND	48*	GPIO_37
49	FlightMode	50	STATUS
51	DBG_TXD	52	NETLIGHT
53	GND	54	GND
55	GNSS_ANT	56	GND

*Note: SIM7500A could not support GNSS Function.

Before the normal power up, pin48 cannot be pulled up.



2.2 Pin Description

Table 4: IO parameters definition

Pin type	Description
PI	Power input
PO	Power output
AI	Analog input
AIO	Analog input/output
I/O	Bidirectional input /output
DI	Digital input
DO	Digital output
DOH	Digital output with high level
DOL	Digital output with low level
PU	Pull up
PD	Pull down

Table 5: Pin description

Pin name	Pin No.	Default status	Description	Comment			
Power Supply							
VBAT	33,34	PI	Power supply, voltage range: 3.4~4.2V.				
L11_1V8	23	PO	1.8V output with Max. 50ma current output for external circuit, such as level shift circuit.	If unused, keep it open.			
GND	1, 3, 6, 15,16,22,28,29,3 1,32,35, 43,44,46,47,53,5 4,56		Ground				
System Control							
PWRKEY	30	DI,PU	System power on/off control input, active low.	Default 0.8V			
RESET	24	DI, PU	System reset control input, active low.	RESET has been pulled up to 1.8V via a resistor internally.			
SIM interface							
SIM_DATA	10	I/O,PU	SIM Card data I/O, which has been pulled up via a 100KR resistor to SIM_VDD internally.	All lines of SIM interface should be protected			



A company of SIM Tech			Smart Mach	ine Smart Decision
SIM_RST	13	DO	SIM Reset	against ESD.
SIM_CLK	11	DO	SIM clock	
SIM_VDD	14	РО	Power output for SIM card, its output Voltage depends on SIM card type automatically. Its output current is up to 50ma.	
USB				
VBUS	9	DI,PD	Valid USB detection input with 3.0∼5.25V detection voltage	
USB_DM	7	I/O	Negative line of the differential, bi-directional USB signal.	
USB_DP	8	I/O	Positive line of the differential, bi-directional USB signal.	
UART interface	e			
RTS	36	DOH	Request to send	
CTS	41	DI,PU	Clear to Send	
RXD	39	DI,PU	Receive Data	If unused, keep
RI	42	DOH	Ring Indicator	them open.
DCD	37 DOH Carrier detects		mem open.	
TXD	38	DOH	Transmit Data	
DTR	40	DI,PU	DTE get ready	
I2C interface				
SCL	4	DO	I2C clock output	If unused, keep
SDA	5	I/O	I2C data input/output	them open.
PCM interface				
PCM_OUT	21	DO	PCM data output.	
PCM_IN	20	DI	PCM data input.	If unused, please
PCM_SYNC	19	DO	PCM data frame sync signal.	keep them open.
PCM_CLK	18	DO	PCM data bit clock.	
I2S_MCLK	17	DO	Audio Master clock	
GPIO	7			
NETLIGHT	52	DO	LED control output as network status indication.	
STATUS	50	DO	Operating status output. High level: Power on and firmware ready Low level: Power off	If unused, please keep them open.
GPIO_1	26	IO	GPIO	FlightMode Can't
FlightMode	49	DI,PU	Flight Mode control input. High level(or open): Normal Mode Low level: Flight Mode	be used when Module is in sleep mode.
SIM_DET	12	Ю	Default: GPIO Optional: SIM card detecting input. H: SIM is removed	



A company or Sav. Isicn	Smart Machine Smart Decision				
			L: SIM is inserted		
GPIO_37	48	IO	GPIO		
RF interface					
MAIN _ANT	45	AIO	MAIN antenna soldering pad		
DIV_ANT	2	AI	Auxiliary antenna soldering pad		
GNSS_ANT	55	AI	GNSS antenna soldering pad		
Other interface					
ISINK	27	AI	Ground-referenced current sink.		
DGB_TXD	51	DO	Use for debug If unused, keep them of		
ADC	25	AI	Analog-digital converter input		

2.3 Mechanical Information

The following figure shows the package outline drawing of Module.

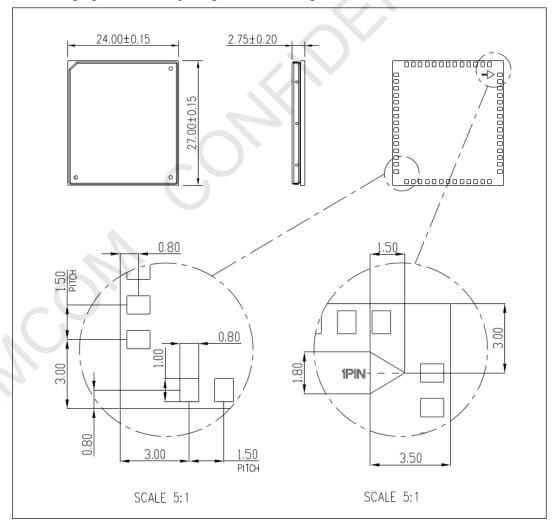


Figure 3: Dimensions (Unit: mm)



2.4 Footprint Recommendation

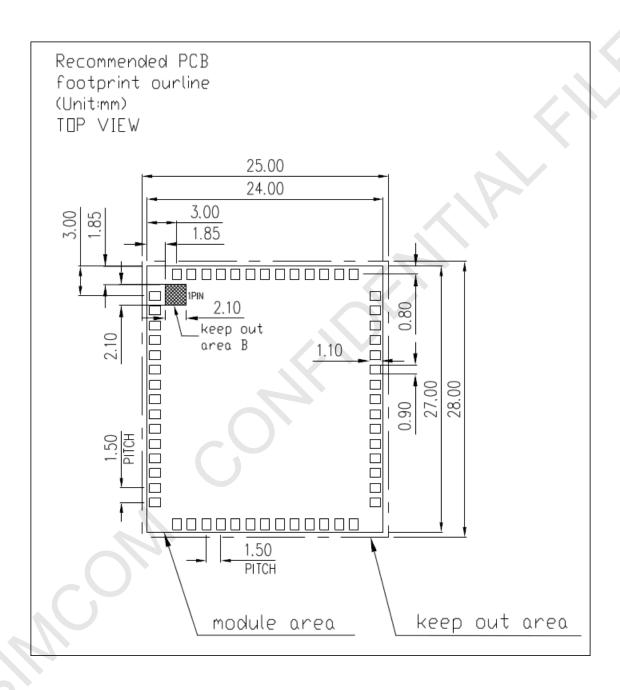


Figure 4: Footprint recommendation (Unit: mm)



3 Interface Application

3.1 Power Supply

On VBAT pads, a ripple current up to 2A typically, may cause voltage drop. Therefore, the power supply for these pads must be able to provide sufficient current up to more than 2A in order to avoid the voltage drop of more than 300mV.

Table 6: VBAT Pins electronic characteristic

Symbol	Description	Min.	Typ.	Max.	Unit
VBAT	Module power voltage		3.8	4.2	V
I _{VBAT(peak)}	Module power peak current in normal mode.	1.0	1-1	2	A
I _{VBAT(average)}	Module power average current in normal mode	Dlagge	rafor to t	ha tahla	2.4
I _{VBAT(sleep)}	Power supply current in sleep mode Please refer to the table 3		34		
$I_{VBAT(power-off)}$	Module power current in power off mode.		-	20	uA

3.1.1 Power supply Design Guide

Make sure that the voltage on the VBAT pins will never drop below 3.4V.

Note: If the power supply for BAT pins can support up to 2A, using a total of more than 220uF capacitors is recommended, or else users must use a total of 1000uF capacitors, in order to avoid the voltage drop of more than 300mV.

Some multi-layer ceramic chip (MLCC) capacitors (0.1/1uF) with low ESR in high frequency band can be used for EMC.

These capacitors should be put as close as possible to VBAT pads. Also, user should keep VBAT trace on the circuit board wider than 2 mm to minimize PCB trace impedance. The following figure shows the recommended circuit.

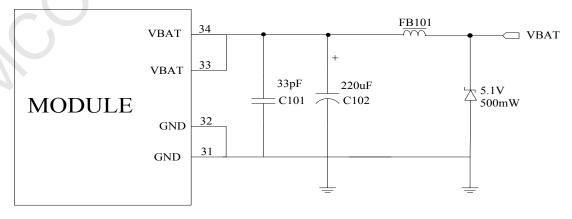


Figure 5: Power supply application circuit SIM7500A_SIM7500E_SIM7500JC_SIM7500S_SIM7500SA_Hardware Design_V1.02 2017-01-03



In addition, in order to guard over voltage protection, it is suggested to use a zener diode with 5.1V reverse zener voltage and more than 500mW power dissipation.

Table 7: Recommended zener diode list

No.	Manufacturer	Part Number	power dissipation	Package
1	On semi	MMSZ5231BT1G	500mW	SOD123
2	Prisemi	PZ3D4V2H	500mW	SOD323
3	Vishay	MMSZ4689-V	500mW	SOD123
4	Crownpo	CDZ55C5V1SM	500mW	0805

3.1.2 Recommended Power Supply Circuit

It is recommended that a switching mode power supply or linear regulator power supply is used. It is important to make sure that all the components used in the power supply circuit can resist a peak current up to 2A.

The following figure shows the linear regulator reference circuit with 5V input and 3.8V output.

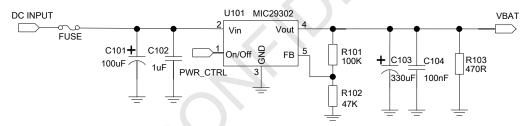


Figure 6: Linear regulator reference circuit

If there is a big voltage difference between input and output for VBAT power supply, or the efficiency is extremely important, then a switching mode power supply will be preferable. The following figure shows the switching mode power supply reference circuit.

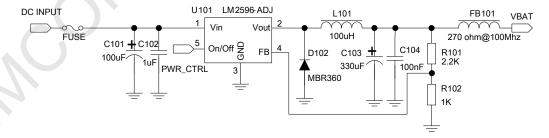


Figure 7: Switching mode power supply reference circuit

Note: The Switching Mode power supply solution for VBAT must be chosen carefully against Electro Magnetic Interference and ripple current from depraving RF performance.



3.1.3 Voltage Monitor

To monitor the VBAT voltage, the AT command "AT+CBC" can be used.

For monitoring the VBAT voltage outside or within a special range, the AT command

"AT+CVALARM" can be used to enable the under-voltage warning function.

If users need to power off Module, when the VBAT voltage is out of a range, the AT command "AT+CPMVT" can be used to enable under-voltage power-off function.

Note: Under-voltage warning function and under-voltage power-off function are disabled by default. For more information about these AT commands, please refer to Document [1].

3.2 Power on/Power off/Reset Function

3.2.1 Power on

Module can be powered on by pulling the PWRKEY pin down to ground.

The PWRKEY pin has been pulled up with a diode to 1.8V internally, so it does not need to be pulled up externally. It is strongly recommended to put a100nF capacitor, an ESD protection diode, close to the PWRKEY pin as it would strongly enhance the ESD performance of PWRKEY pin. Please refer to the following figure for the recommended reference circuit.

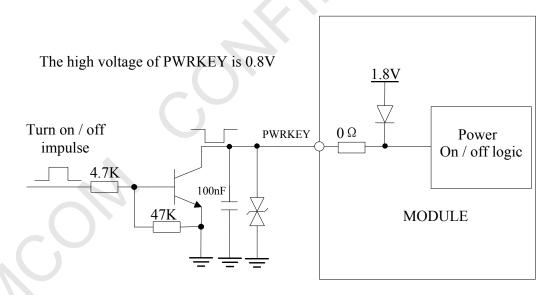


Figure 8: Reference Power on/off Circuit

Note: Module could be automatically power on by connecting PWRKEY pin to ground via 0R resistor directly.

The power-on scenarios are illustrated in the following figure.



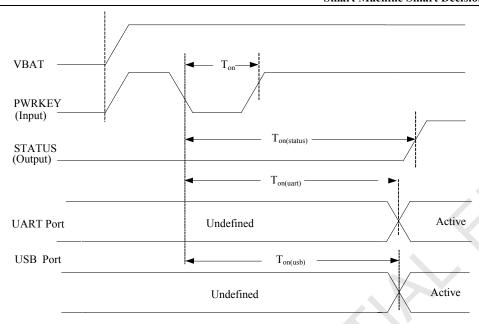


Figure 9: Power on timing sequence

Table 8: Power on timing and electronic characteristic

~		7.51	-	7.5	A.
Symbol	Parameter	Min.	Typ.	Max.	Unit
Ton	The time of active low level impulse of PWRKEY pin to power on module	100	500	-	ms
T _{on(status)}	The time from power-on issue to STATUS pin output high level(indicating power up ready)	12	13	-	S
T _{on(uart)}	The time from power-on issue to UART port ready	11	12		S
T _{on(usb)}	The time from power-on issue to USB port ready	11	12		S
V_{IH}	Input high level voltage on PWRKEY pin	0.6	0.8	1.8	V
V_{IL}	Input low level voltage on PWRKEY pin	-0.3	0	0.5	V

3.2.2 Power off

The following methods can be used to power off Module.

- Method 1: Power off Module by pulling the PWRKEY pin down to ground.
- Method 2: Power off Module by AT command "AT+CPOF".
- Method 3: Over-voltage or under-voltage automatic power off. The voltage range can be set by AT command "AT+CPMVT".
- Method 4: Over-temperature or under-temperature automatic power off.

Note: If the temperature is outside the range of -30 \sim +80 °C, som e warning will be reported via AT port. If the temperature is outside the range of -40 \sim +85 °C, M odu le will be powered of



automatically.

For details about "AT+CPOF" and "AT+CPMVT", please refer to Document [1].

These procedures will make modules disconnect from the network and allow the software to enter a safe state and save data before modules are powered off completely.

The power off scenario by pulling down the PWRKEY pin is illustrated in the following figure.

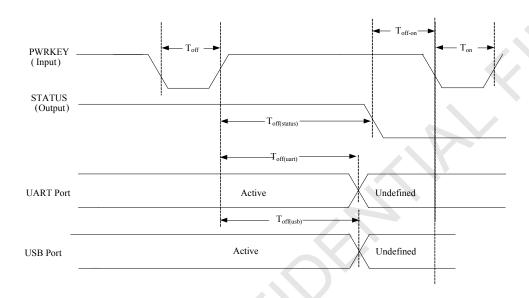


Figure 10: Power off timing sequence

Table 9: Power off timing and Electronic Characteristic

Chl	Parameter		Time value		
Symbol			Typ.	Max.	Unit
T _{off}	The active low level time pulse on PWRKEY pin to power off module				S
$T_{off(status)}$	The time from power-off issue to STATUS pin output low level(indicating power off)*	25	26	-	S
T _{off(uart)}	The time from power-off issue to UART port off	14	15	-	S
$T_{off(usb)}$	The time from power-off issue to USB port off	27	28	-	S
T _{off-on}	The buffer time from power-off issue to power-on issue	0	-	-	S



3.2.3 Reset Function

Module can be reset by pulling the RESET pin down to ground.

Note: This function is only used as an emergency reset when AT command "AT+CPOF" and the PWRKEY pin all have lost efficacy.

The RESET pin has been pulled up to 1.8V internally, so it does not need to be pulled up externally. It is strongly recommended to put a100nF capacitor and an ESD protection diode close to the RESET pin. Please refer to the following figure for the recommended reference circuit.

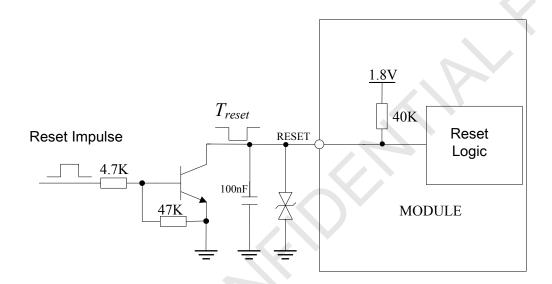


Figure 11: Reference reset circuit

Table 10: RESET pin electronic characteristic

Symbol	Description		Typ.	Max.	Unit
T _{reset}	The active low level time impulse on RESET pin to reset module	100			ms
V_{IH}	Input high level voltage	1.17	1.8	2.1	V
V_{IL}	Input low level voltage	-0.3	0	0.8	V

3.3 UART Interface

Module provides a 7-wire UART (universal asynchronous serial transmission) interface as DCE (Data Communication Equipment). AT commands and data transmission can be performed through UART interface.



3.3.1 UART Design Guide

The following figures show the reference design.

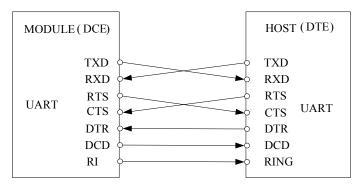


Figure 12: UART full modem

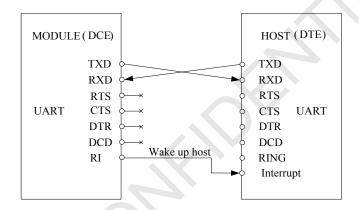


Figure 13: UART null Modem

The Module UART is 1.8V voltage interface. If user's UART application circuit is a 3.3V voltage interface, the level shifter circuits should be used for voltage matching. The TXB0108RGYR provided by Texas Instruments is recommended. The following figure shows the voltage matching reference design.

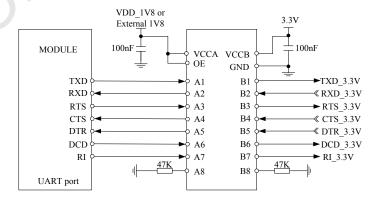


Figure 14: Reference circuit of level shift

To comply with RS-232-C protocol, the RS-232-C level shifter chip should be used to connect



Module to the RS-232-C interface, for example SP3238ECA, etc.

Note: Module supports the following baud rates: 300, 600, 1200, 2400, 4800, 9600, 19200, 38400, 57600, 115200, 230400, 460800, 921600, 3200000, 3686400, 4000000bps. The default band rate is 115200bps.

3.3.2 RI and DTR Behavior

The RI pin can be used to interrupt output signal to inform the host controller such as application CPU.

Normally RI will stay at high level until certain conditions such as receiving SMS, or a URC report come in. It will then change to low level. It will stay low until the host controller clears the interrupted event with "AT+CRIRS" AT command.

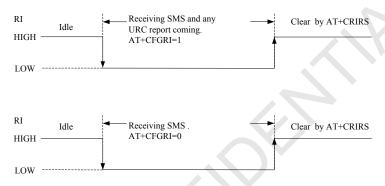


Figure 15: RI behaviour (SMS and URC report)

Normally RI will be kept high until a voice call, then it will output periodic rectangular wave with 5900ms low level and 100ms high level. It will output this kind of periodic rectangular wave until the call is answered or hung up.

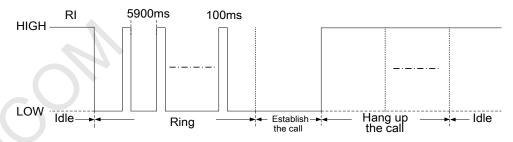


Figure 16: RI behaviour (voice call)

Note: For more details of AT commands about UART, please refer to document [1] and [22].

DTR pin can be used to wake Module from sleep. When Module enters sleep mode, pulling down DTR can wake Module.



3.4 USB Interface

The Module contains a USB interface compliant with the USB2.0 specification as a peripheral, but the USB charging function is not supported.

3.4.1 USB Application Guide

Module can be used as a USB device. Module supports the USB suspend and resume mechanism which can reduce power consumption. If there is no data transmission on the USB bus, Module will enter suspend mode automatically and will be resumed by some events such as voice call, receiving SMS, etc.

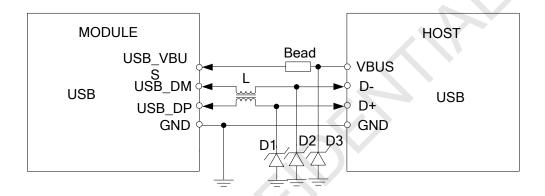


Figure 17: USB reference circuit

Because of the high bit rate on USB bus, more attention should be paid to the influence of the junction capacitance of the ESD component on USB data lines. Typically, the capacitance should be less than 1pF. It is recommended to use an ESD protection component such as ESD9L5.0ST5G provided by On Semiconductor (www.onsemi.com).

D3 is suggested to select the diode with anti-ESD and voltage surge function, or customer could add a ZENER diode for surge clamping. The recommend diodes list please refer to table 7. L is recommended (MURATA) DLW21SN371SQ2L.

Note: The USB_DM and USB_DP nets must be traced by 900hm+/-10% differential impedance.

3.5 SIM Interface

Module supports both 1.8V and 3.0V SIM Cards.

Table 11: SIM Electronic characteristic in 1.8V mode (SIM_VDD=1.8V)

Symbol	Parameter	Min.	Typ.	Max.	Unit
SIM_V DD	LDO power output voltage	1.75	1.8	1.95	V



V_{IH}	High-level input voltage	0.65*SIM_VDD	-	SIM_VDD +0.3	V
$V_{\rm IL}$	Low-level input voltage	-0.3	0	0.35*SIM_VDD	V
V_{OH}	High-level output voltage	SIM_VDD -0.45	-	SIM_VDD	V
V_{OL}	Low-level output voltage	0	0	0.45	V

Table 12: SIM Electronic characteristic 3.0V mode (SIM VDD=2.95V)

Symbol	Parameter	Min.	Typ.	Max.	Unit
SIM_V DD	LDO power output voltage	2.75	2.95	3.05	V
V_{IH}	High-level input voltage	0.65*SIM_VDD	-	SIM_VDD +0.3	V
V_{IL}	Low-level input voltage	-0.3	0	0.25*SIM_VDD	V
V_{OH}	High-level output voltage	SIM_VDD -0.45		SIM_VDD	V
V_{OL}	Low-level output voltage	0	0	0.45	V

3.5.1 SIM Application Guide

It is recommended to use an ESD protection component such as ESDA6V1W5 produced by ST (www.st.com) or SMF15C produced by ON SEMI (www.onsemi.com). Note that the SIM peripheral circuit should be close to the SIM card socket. The following figure shows the 8-pin SIM card holder reference circuit.

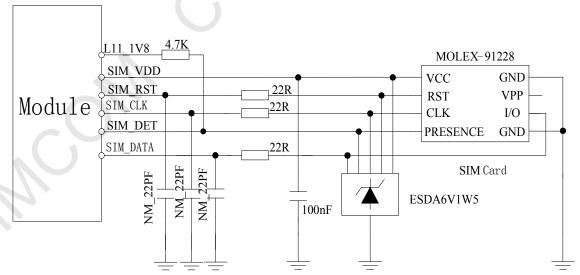


Figure 18: Reference circuit of the 8-pin SIM card holder

The SIM_DET pin is used for detection of the SIM card hot plug in. User can select the 8-pin SIM card holder to implement SIM card detection function.



If the SIM card detection function is not used, user can keep the SIM_DET pin open. The reference circuit of 6-pin SIM card holder is illustrated in the following figure.

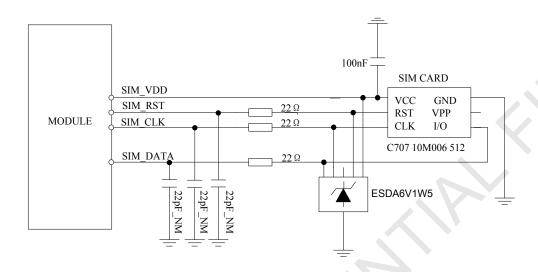


Figure 19: SIM interface reference circuit

Note: SIM_DATA has been pulled up with a 100K\Omega resistor to SIM_VDD in module. A 100nF capacitor on SIM_VDD is used to reduce interference. For more details of AT commands about SIM, please refer to document [1].

3.5.2 SIM Card Design Guide

SIM card signal could be interferenced by some high frequency signal, it is strongly recommended to follow these guidelines while designing:

- SIM card holder should be far away from main antenna
- SIM traces should keep away from RF lines, VBAT and high-speed signal lines
- The traces should be as short as possible
- Keep SIM card holder's GND connect to main ground directly
- Shielding the SIM card signal by ground well
- Recommended to place a 100nF capacitor on SIM_VDD line and keep close to the SIM card holder
- Add some TVS which parasitic capacitance should not exceed 50pF
- Add 22Ω resistor to (SIM_RST/SIM_CLK/SIM_DATA) signal could enhance ESD protection
- Mount 22pF capacitor to (SIM_RST/SIM_CLK/SIM_DATA) signal if having RF signal interference



3.5.3 Recommended SIM Card Holder

It is recommended to use the 6-pin SIM socket such as C707 10M006 512 produced by Amphenol. User can visit http://www.amphenol.com for more information about the holder.

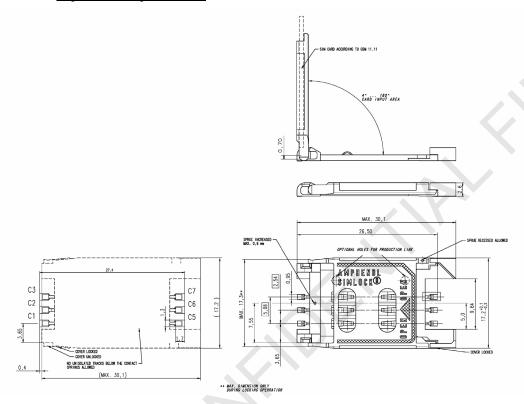


Figure 20: Amphenol SIM card socket

Table 13: Amphenol SIM Socket Pin Description

Pin	Signal	Description
C1	SIM_VDD	SIM Card Power supply.
C2	SIM_RST	SIM Card Reset.
C3	SIM_CLK	SIM Card Clock.
C5	GND	Connect to GND.
C6	VPP	
C7	SIM_DATA	SIM Card data I/O.

3.6 PCM Interface

Module provides a PCM interface for external codec, which can be used in master mode with short sync and 16 bits linear format.

Table 14: PCM Format



Line Interface Format	Linear(Fixed)
Data length	16bits(Fixed)
PCM Clock/Sync Source	Master Mode(Fixed)
PCM Clock Rate	2048 KHz (Fixed)
PCM Sync Format	Short sync(Fixed)
Data Ordering	MSB

Note: For more details about PCM AT commands, please refer to document [1].

3.6.1 PCM Timing

Module supports 2.048 MHz PCM data and sync timing for 16 bits linear format codec.

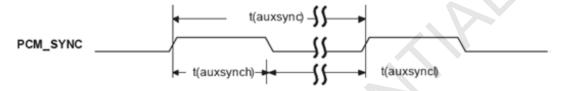


Figure 21: PCM_SYNC timing

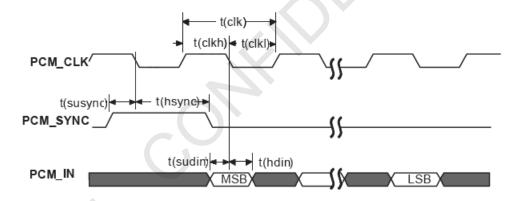


Figure 22: EXT codec to module timing

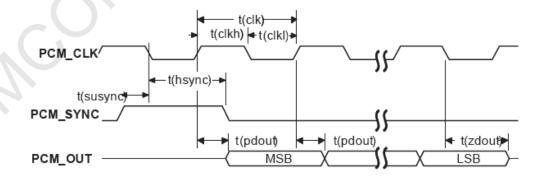


Figure 23: Module to EXT codec timing

Table 15: PCM Timing Parameters



Parameter	Description	Min.	Typ.	Max.	Unit
T(sync)	PCM_SYNC cycle time	-	125	_	μs
T(synch)	PCM_SYNC high level time	-	488	-	ns
T(syncl)	PCM_SYNC low level time	_	124.5	_	μs
T(clk)	PCM_CLK cycle time	-	488	-	ns
T(clkh)	PCM_CLK high level time	-	244	-	ns
T(clkl)	PCM_CLK low level time	-	244	-	ns
T(susync)	PCM_SYNC setup time high before falling edge of PCM_CLK	-	122	-	ns
T(hsync)	PCM_SYNC hold time after falling edge of PCM_CLK	-	366	-	ns
T(sudin)	PCM_IN setup time before falling edge of PCM_CLK	60	-0	-/	ns
T(hdin)	PCM_IN hold time after falling edge of PCM_CLK	60	-	-	ns
T(pdout)	Delay from PCM_CLK rising to PCM_OUT valid		-	60	ns
T(zdout)	Delay from PCM_CLK falling to PCM_OUT HIGH-Z	-	-	60	ns

3.6.2 PCM Application Guide

The following figure shows the external codec reference design.

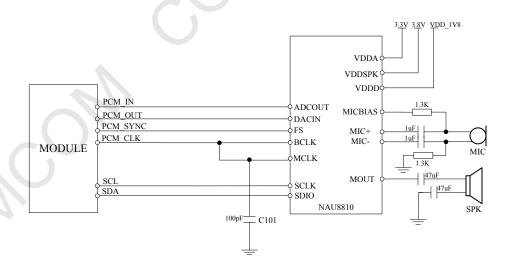


Figure 24: Audio codec reference circuit

Note: 1. Module can transmit PCM data by the USB port besides the PCM interface. For more details please refer to documents [1] and [23].

- 2. If use SIM7500E Module,C101 should use 220pF.
- 3.C101 must be mounted.



3.7 I2C Interface

Module provides a I2C interface compatible with I2C specification, version 2.1, with clock rate up to 400 kbps. Its operation voltage is 1.8V.

3.7.1 I2C Design Guide

The following figure shows the I2C bus reference design.

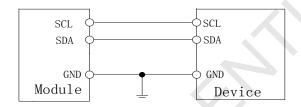


Figure 25: I2C reference circuit

Note:

SDA and SCL have pull-up resistors in module. So, 2 external pull up resistors are not needed in application circuit.

"AT+CRIIC and AT+CWIIC" AT commands could be used to read/write register values of the 12C peripheral devices. For more details about AT commands please refer to document [1].

3.8 Network Status

The NETLIGHT pin is used to control Network Status LED, its reference circuit is shown in the following figure.

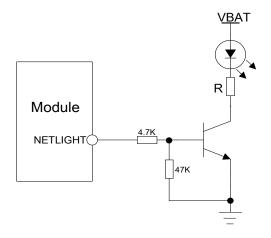




Figure 26: NETLIGHT reference circuit

Note: The value of the resistor named "R" depends on the LED characteristic.

Table 16: NETLIGHT pin status

NETLIGHT pin status	Module status	
Always On	Searching Network/Call Connect	
200ms ON, 200ms OFF	Data Transmit	
800ms ON, 800ms OFF	Registered network	
OFF	Power off / Sleep	

Note: NETLIGHT output low level as "OFF", and high level as "ON".

3.9 Operating Status Indication

The pin50 is for operating status indication of the module. The pin output is high when module is powered on, and output is low when module is powered off.

Table 17: Pin definition of the STATUS

Pin name	Pin number	Description
STATUS	50	Operating status indication

Note: For timing about STATUS, please reference to the chapter "3.2 power on/down scenarios"

3.10 Flight Mode Control

The FLIGHTMODE pin can be used to control SIM7500x to enter or exit the Flight mode. In Flight mode, the RF circuit is closed to prevent interference with other equipments and minimize current consumption. Bidirectional ESD protection component is suggested to add on FLIGHTMODE pin, its reference circuit is shown in the following figure.

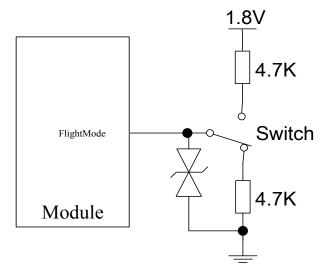




Figure 27: Flight Mode Switch Reference Circuit

Table 18: FLIGHTMODE Pin Status

Module operation	
Flight Mode: RF is closed	
AT+CFUN=0: RF is closed	
	Flight Mode: RF is closed

Note: Flight Mode Can't be used when Module is in sleep mode.

3.11 Pin Multiplex Function

Some pins of Module could be used for alternate function besides default function.

Table 19: Pin multiplex function list

Pin Number	Pin Name	Default Function	Alternate Function
4	SCL	SCL	GPIO11
5	SDA	SDA	GPIO10
12	SIM_DET	GPIO34	SIM_DET
18	PCM_CLK	PCM_CLK	GPIO23,SPI_CLK I2C_SCL
19	PCM_SYNC	PCM_SYNC	GPIO20,SPI_MOSI
20	PCM_IN	PCM_IN,	GPIO21,SPI_MISO
21	PCM_OUT	PCM_OUT	GPIO22,SPI_CS_N I2C_SDA

Note: For more details of AT commands about GPIO multiplex function, please refer to document [1].

3.12 Other interface

3.12.1 Sink Current Source

The ISINK pin is VBAT tolerant and intended to drive some passive devices such as LCD backlight, white LED, etc. Its output current can be up to 40 mA and be set by the AT command "AT+ CLEDITST".

Table 20: Sink current electronic characteristic

Symbol	Description	Min.	Typ.	Max.	Unit
V _{ISINK}	Voltage tolerant	0.5	-	VBAT	V



I_{ISINK}	Current tolerant	0	-	40	mA

ISINK is a ground-referenced current sink. The following figure shows its reference circuit.

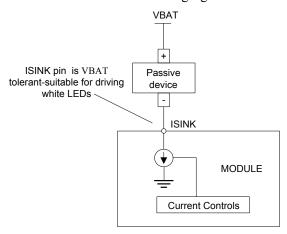


Figure 28: ISINK reference circuit

Note: The sinking current can be adjusted to meet the design requirement through the AT command "AT+ CLEDITST =<0>, <value>".The "value" ranges from 0 to 8, on behalf of the current from 0mA to 40mA by 5mA step.

3.12.2 ADC

Module has 1 dedicated ADC pins named ADC. They are available for digitizing analog signals such as battery voltage and so on. These electronic specifications are shown in the following table.

Table 21: ADC Electronic Characteristics

Characteristics	Min.	Typ.	Max.	Unit
Resolution	_	15	-	Bits
Input Range	0.1		1.7	V
Input serial resistance	1	_	-	$M\Omega$

Note: "AT+CADC" can be used to read the voltage of the ADC pins, for more details, please refer to document [1].



4 RF Specifications

4.1 WCDMA/LTE RF Specifications

Table 22: Conducted transmission power

Frequency	Power	Min.
E-GSM900	33dBm ±2dB	$5dBm \pm 5dB$
DCS1800	30 dBm ± 2 dB	$0dBm \pm 5dB$
E-GSM900 (8-PSK)	27dBm ±3dB	$5dBm \pm 5dB$
DCS1800 (8-PSK)	26dBm +3/-4dB	0dBm ±5dB
WCDMA B1	24dBm +1/-3dB	<-50dBm
WCDMA B2	24dBm +1/-3dB	<-50dBm
WCDMA B5	24dBm +1/-3dB	<-50dBm
LTE-FDD B1	23dBm +/-2.7dB	<-40dBm
LTE-FDD B2	23dBm +/-2.7dB	<-40dBm
LTE-FDD B3	23dBm +/-2.7dB	<-40dBm
LTE-FDD B4	23dBm +/-2.7dB	<-40dBm
LTE-FDD B5	23dBm +/-2.7dB	<-40dBm
LTE-FDD B7	23dBm +/-2.7dB	<-40dBm
LTE-FDD B8	23dBm +/-2.7dB	<-40dBm
LTE-FDD B12	23dBm +/-2.7dB	<-40dBm
LTE-FDD B18	23dBm +/-2.7dB	<-40dBm
LTE-FDD B19	23dBm +/-2.7dB	<-40dBm
LTE-FDD B20	23dBm +/-2.7dB	<-40dBm
LTE-FDD B25	23dBm +/-2.7dB	<-40dBm
LTE-FDD B26	23dBm +/-2.7dB	<-40dBm
LTE-FDD B28	23dBm +/-2.7dB	<-40dBm

Table 23: Operating frequencies

Frequency	Receiving	Transmission
E-GSM900	925~960 MHz	880~915 MHz
DCS1800	1805~1880 MHz	1710~1785 MHz
WCDMA B1	2110 ~2170 MHz	1920 ~1980 MHz
WCDMA B2	1930~1990 MHz	1850~1910 MHz
WCDMA B5	869~894 MHz	824~849 MHz
WCDMA B8	925~960 MHz	880 ~915 MHz
LTE-FDD B1	2110 ~2170 MHz	1920 ~1980 MHz
LTE-FDD B2	1930 ~1990 MHz	1850 ~1910 MHz
LTE-FDD B3	1805 ~1880 MHz	1710 ~1785 MHz
LTE-FDD B4	2110 ~2155 MHz	1710 ~1755 MHz
LTE-FDD B5	869~894 MHz	824~849 MHz
LTE-FDD B7	2620~2690 MHz	2500 ~2570 MHz
LTE-FDD B8	925~960 MHz	880 ~915 MHz



LTE-FDD B12	729 ~746 MHz	699 ~716 MHz
LTE-FDD B18	860 ~875 MHz	815~830 MHz
LTE-FDD B19	875 ~890 MHz	830~845 MHz
LTE-FDD B20	832 ~862 MHz	791~821 MHz
LTE-FDD B25	1930 ~1995 MHz	1850~1850 MHz
LTE-FDD B26	859 ~894 MHz	814~849 MHz
LTE-FDD B28	758 ~803 MHz	703~748 MHz
GPS	1574.4 ∼1576.44 MHz	-
GLONASS	1598 ∼1606 MHz	-
BD	1559 ∼1563 MHz	

Table 24: Conducted receive sensitivity

Frequency	Receive sensitivity(Typical)	Receive sensitivity(MAX)			
E-GSM900	<-109dBm	3GPP			
DCS1800	<-109dBm	3GPP			
WCDMA 2100	<-110dBm	3GPP			
WCDMA 1900	<-110dBm	3GPP			
WCDMA 900	<-110dBm	3GPP			
WCDMA 850	<-110dBm	3GPP			
TDSCDMA 1900	<-110dBm	3GPP			
TDSCDMA 2000	<-110dBm	3GPP			
CDMA BC0	<-110dBm	3GPP			
LTE FDD/TDD	See table 25.	3GPP			

Table 25: Reference sensitivity (QPSK)

E-UTRA		3GPP standard			Test value	3GPP standard		Dunley
band	1.4 MHz	3MHz	5MHz	10MHz	10 MHz	15 MHz	20 MHz	Duplex
1	-	-	-100	-97	-101.3	-95.2	-94	FDD
2	-102.7	-99.7	-98	-95	-101	-93.2	-92	FDD
3	-101.7	-98.7	-97	-94	-100	-92.2	-91	FDD
4	-104.7	-101.7	-100	-97	-102	-95.2	-94	FDD
5	-103.2	-100.2	-98	-95	-101	-	-	FDD
7	-	-	-98	-95	-98	-93.2	-92	FDD
8	-102.2	-99.2	-97	-94	-99.8	-	-	FDD
12	-101.7	-98.7	-97	-94	-101.5	-	-	FDD
18	-	-	-100	-97	-101	-95.2	-	FDD
19	-	-	-100	-97	-101	-95.2	-	FDD



20	-	-	-97	-94	-102	-91.2	-90	FDD
25	-101.2	-98.2	-96.5	-93.5	-100	-91.7	-90.5	FDD
26	-102.7	-99.7	-97.5	-94.5	-101	-92.7	-	FDD
28		-100.2	-98.5	-95.5	TBD	-93.7	-91	FDD

4.2 GSM/WCDMA/LTE Antenna Design Guide

Users should connect antennas to Module's antenna pads through the micro-strip line or other types of RF trace. The trace impedance must be controlled in 50Ω . SIMCom recommends that the total insertion loss between Module and antenna should meet the following requirements:

Table 26: Trace Loss

Frequency	Loss
700MHz-960MHz	<0.5dB
1710MHz-2170MHz	<0.9dB
2300MHz-2650MHz	<1.2dB

To facilitate the antenna tuning and certification test, a RF connector and an antenna matching circuit should be added. The following figure is the recommended circuit.

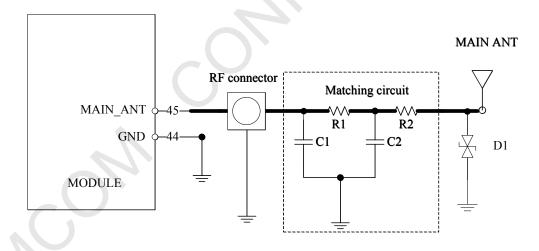


Figure 29: Antenna matching circuit (MAIN_ANT)

In above figure, the components R1,C1,C2 and R2 are used for antenna matching, the value of components can only be achieved after the antenna tuning and usually provided by antenna vendor. By default, the R1, R2 are 0Ω resistors, and the C1, C2 are reserved for tuning. The component D1 is a TVS for ESD protection, and it is optional for users according to application environment. The RF test connector is used for the conducted RF performance test, and should be placed as close as to the module's MAIN_ANT pin. The traces impedance between Module and antenna must be SIM7500A_SIM7500E_SIM7500JE_SIM7500JC_SIM7500S_SIM7500SA_Hardware Design_V1.02 37 2017-01-03



controlled in 50Ω .

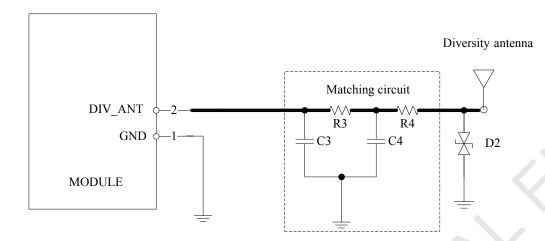


Figure 30: Antenna matching circuit (DIV ANT)

In above figure, R3, C3, C4 and R4 are used for auxiliary antenna matching. By default, the R3, R4 are 0Ω resistors, and the C3, C4 are reserved for tuning. D2 is a TVS for ESD protection, and it is optional for users according to application environment.

Two TVS are recommended in the table below.

Table 27: Recommended TVS

Package	Part Number	Vender
0201	LXES03AAA1-154	Murata
0402	LXES15AAA1-153	Murata

Note: SIMCom suggests the LTE auxiliary antenna to be kept on, since there are many high bands in the designing of FDD-LTE. Because of the high insert loss of the RF cable and layout lines, the receiver sensitivity of these bands above will have risk to meet the authentication without the diversity antenna. For more details about auxiliary antenna design notice, please refer to document [25]

4.3 GNSS

SIM7500 series merges GNSS satellite and network information to provide a high-availability solution that offers industry-leading accuracy and performance. This solution performs well, even in very challenging environmental conditions where conventional GNSS receivers fail, and provides a platform to enable wireless operators to address both location-based services and emergency mandates.

4.3.1 GNSS Technical specification

- Tracking sensitivity: -159 dBm (GPS) /-158 dBm (GLONASS)
- Cold-start sensitivity: -148 dBm



• Accuracy (Open Sky): 2.5m (CEP50)

• TTFF (Open Sky): Hot start <1s, Cold start <35s

Receiver Type: 16-channel, C/A Code
GPS L1 Frequency: 1575.42±1.023MHz

GLONASS: 1597.5~1605.8 MHz

• Update rate: Default 1 Hz

• GNSS data format: NMEA-0183

GNSS Current consumption: 100mA ((WCDMA/LTE Sleep ,in total on VBAT pins)

GNSS antenna: Passive/Active antenna

Note: If the antenna is active type, the power should be given by main board, because there is no power supply on GPS antenna pad. If the antenna is passive, it is suggested that the external LNA should be used.

4.3.2 GNSS Application Guide

Users can adopt an active antenna or a passive antenna as GNSS signal transceiver. In this document, all GNSS specification mentioned is from passive antenna. The following is the reference circuit.

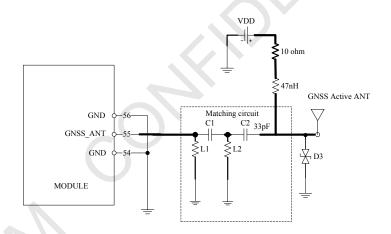


Figure 31: Active antenna circuit

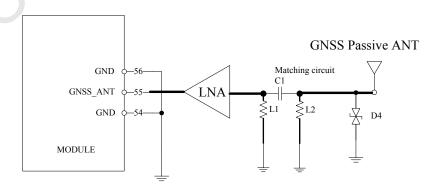


Figure 32: Passive antenna circuit (Default)



In above figures, the components C1 and L1, L2 are used for antenna matching, the values of the components can only be obtained after the antenna tuning and usually provided by antenna vendor. C2 in Figure 29 is used for DC blocking. L3 is the matching component of the external LNA, and the value of L3 is determined by the LNA characteristic and PCB layout. Both VDD of active antenna and V_LNA need external power supplies which should be considered according to active antenna and LNA characteristic. LDO/DCDC is recommended to get lower current consuming by shutting down active antennas and LNA when GNSS is not working.

LNA should apply the following requirements as table 28. LNA is also suggested to put near the passive antenna.

Table 28: LNA requirements

	Min	Max	Unit
Vdd	1.5	3.3	V
Idd		3	mA
LNA_EN	1.3		V
Gain	14	17	dB
VSWR		2	

GNSS can be used by NMEA port. User can select NMEA as output through UART or USB. NMEA sentences are automatic and no command is provided. NMEA sentences include GSV, GGA, RMC, GSA, and VTG. Before using GNSS, user should configure SIM7500 series in proper operating mode by AT command. Please refer to related document for details. SIM7500 series can also get position location information through AT directly.

Note: GNSS is closed by default, it could be started by AT+CGPS. The AT command has two parameters, the first is on/off, and the second is GNSS mode. Default mode is standalone mode. AGPS mode needs more support from the mobile telecommunication network. Please refer to document [24] for more details.



5 Electrical Specifications

5.1 Absolute Maximum Ratings

Absolute maximum rating for digital and analog pins of Module are listed in the following table:

Table 29: Absolute maximum ratings

Parameter	Min.	Max.	Unit
Voltage at VBAT	-0.5	6.0	V
Voltage at VBUS	-0.5	6.3	V
Voltage at digital pins (RESET,SPI,GPIO,I2C,UART,PCM)	-0.3	2.1	V
Voltage at digital pins :SIM	-0.3	3.05	V
Voltage at PWRKEY	-0.3	1.8	

5.2 Operating Conditions

Table 30: Recommended operating ratings

Parameter	Min.	Typ.	Max.	Unit
Voltage at VBAT	3.4	3.8	4.2	V
Voltage at VBUS	3.0	5	5.25	V

Table 31: 1.8V Digital I/O characteristics*

Parameter	Description	Min.	Тур.	Max.	Unit
V_{IH}	High-level input voltage	1.17	1.8	2.1	V
$V_{\rm IL}$	Low-level input voltage	-0.3	0	0.63	V
V _{OH}	High-level output voltage	1.35	-	1.8	V
V _{OL}	Low-level output voltage	0	-	0.45	V
I_{OH}	High-level output current(no pull down resistor)	-	2		mA
I_{OL}	Low-level output current(no pull up resistor)	-	-2	-	mA
I_{IH}	Input high leakage current (no pull down resistor)	-	-	1	uA
$I_{\rm IL}$	Input low leakage current(no pull up resistor)	-1	-		uA

^{*}Note: These parameters are for digital interface pins, such as SPI, GPIOs (NETLIGHT), 12C, UART, PCM.



The operating temperature of Module is listed in the following table.

Table 32: Operating temperature

Parameter	Min.	Typ.	Max.	Unit
Normal operation temperature	-30	25	80	$^{\circ}$ C
Extended operation temperature*	-40	25	85	$^{\circ}$
Storage temperature	-45	25	+90	\mathbb{C}

^{*}Note: Module is able to make and receive voice calls, data calls, SMS and make WCDMA/HSPA+/LTE traffic in -40°C \sim +85°C. The performance will be reduced slightly from the 3GPP specifications if the temperature is outside the normal operating temperature range and still within the extreme operating temperature range.

5.3 Operating Mode

5.3.1 Operating Mode Definition

The table below summarizes the various operating modes of Module series products.

Table 33: Operating mode Definitions

Mode	e	Function
	GSM/WCDMA / LTE Sleep	In this case, the current consumption of module will be reduced to the minimal level and the module can still receive paging message and SMS.
и	GSM/WCDMA / LTE Idle	Software is active. Module is registered to the network, and the module is ready to communicate.
Normal operation	GSM/WCDMA / LTE Talk	Connection between two subscribers is in progress. In this case, the power consumption depends on network settings such as DTX off/on, FR/EFR/HR, hopping sequences, antenna.
Norn	GSM/WCDMA/LTE Standby	Module is ready for data transmission, but no data is currently sent or received. In this case, power consumption depends on network settings.
	GPRS/EDGE/WCDM A / LTE transmission	There is data transmission in progress. In this case, power consumption is related to network settings (e.g. power control level); uplink/downlink data rates, etc.
Minimum functionality mode		AT command "AT+CFUN=0" can be used to set the module to a minimum functionality mode without removing the power supply. In this mode, the RF part of the module will not work and the SIM card will not be accessible, but the serial port and USB port are still accessible. The power consumption in this mode is lower than normal mode.
Fligh	t mode	AT command "AT+CFUN=4" or pulling down the FLIGHTMODE



	-
	pin can be used to set the module to flight mode without removing the
	power supply. In this mode, the RF part of the module will not work
	but the serial port and USB port are still accessible. The power
	consumption in this mode is lower than normal mode.
	Module will go into power off mode by sending the AT command "AT+CPOF" or by pulling down the PWRKEY pin normally. In this
Power off	mode the power management unit shuts down the power supply and
	software is not active. The serial port and USB are is not accessible.

5.3.2 Sleep Mode

In sleep mode, the current consumption of module will be reduced to the minimal level, and module can still receive paging message and SMS.

Several hardware and software conditions must be satisfied together in order to let Module enter into sleep mode:

- 1. UART condition
- 2. USB condition
- 3. Software condition

Note: Before designing, pay attention to how to realize sleeping/waking function and refer to Document [26] for more details.

5.3.3 Minimum Functionality Mode and Flight Mode

Minimum functionality mode ceases a majority function of module, thus minimizing the power consumption. This mode is set by the AT command which provides a choice of the functionality levels.

- AT+CFUN=0: Minimum functionality
- AT+CFUN=1: Full functionality (Default)
- AT+CFUN=4: Flight mode

If Module has been set to minimum functionality mode, the RF function and SIM card function will be closed. In this case, the serial port and USB are still accessible, but RF function and SIM card will be unavailable.

If Module has been set to flight mode, the RF function will be closed. In this case, the serial port and USB are still accessible, but RF function will be unavailable.

When Module is in minimum functionality or flight mode, it can return to full functionality by the AT command "AT+CFUN=1".

5.4 Current Consumption

The current consumption is listed in the table below.



Table 34: Current consumption on VBAT Pins (VBAT=3.8V)

GNSS supply current	GNSS	
(AT+CFUN=0,with USB connection) GSM Sleep mode/Idle Mode GSM/GPRS supply current (GNSS off, without USB connection) UNITS Sleep/Idle Mode WCDMA supply current (without USB connection) Idle mode@ BS_PA_MFRMS=2 Typical: 2.8mA Idle mode@ BS_PA_MFRMS=2 Typical: 1.11mA Idle mode@ DRX=9 Typical: 1.11mA Idle mode@ DRX=9 Typical: 1.11mA Idle mode @DRX=9 Typical: 1.7.5mA LTE Sleep/Idle mode LITE supply current (without USB connection) Idle mode Typical: 1.56mA (without USB connection) Idle mode Typical: 1.56mA (without USB connection) Idle mode Typical: 1.56mA (without USB connection) GSM Talk GSM 900 @power level #5 Typical: 220mA @power level #5 Typical: 220mA WCDMA B2 @Power 22dBm Typical: 162mA UMTS Talk WCDMA B5 @Power 23.48dBm Typical: 320mA DCS1800 (1 Rx,4 Tx) @power level #6 Typical: 230mA DCS1800 (1 Rx,4 Tx) @power level #6 Typical: 370mA DCS1800 (1 Rx,4 Tx) @power level #6 Typical: 275mA FDGE GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 300mA GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 300mA GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 300mA GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 320mA DCS1800 (1 Rx,4 Tx) @power level #8 Typical: 320mA DCS1800 (1 Rx,4 Tx) @power level #8 Typical: 320mA DCS1800 (1 Rx,4 Tx) @power level #8 Typical: 320mA GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 320mA DCS1800 (3 Rx, 2 Tx) @power level #8 Typical: 320mA ISDPA Data #CDMA B2 @Power 24dBm Typical: TBD ### Typical: 54mA ### Typical: 54mA ### Typical: 54mA ### Typical: 55mA ### Typi		
Simular Simu		@ -140dBm, Tracking Typical:72mA
Sleep mode@ BS_PA_MFRMS=2 Typical: 2.8mA	, , ,	
Idle mode@ BS_PA_MFRMS=2 Typical: 18mA		Sleen mode@ BS_PA_MFRMS=2 Typical: 2.8mA
### UNTS Sleep/Idle Mode WCDMA supply current (without USB connection) Idle mode @DRX=9 Typical: 1.11mA (without USB connection) ITE supply current Sleep mode Typical: 1.56mA (without USB connection) Idle mode Typical: 1.56mA (without USB connection) Idle mode Typical: 1.57mA CSM Talk	* * *	. 0 = =
WCDMA supply current Sleep mode @DRX=9 Typical: 1.11mA (without USB connection) Idle mode @DRX=9 Typical: 17.5mA LTE Sleep/Idle mode LTE supply current Sleep mode Typical: 1.56mA (without USB connection) Idle mode Typical: 13.7mA GSM Talk GSM 900 @power level #5 Typical: 220mA DCS1800 @power level #5 Typical: 162mA UMTS Talk WCDMA B2 @Power 22dBm Typical: 524mA WCDMA B5 @Power 23.48dBm Typical: 480mA GPRS GSM 900 (1 Rx,4 Tx) @power level #5 Typical: 230mA DCS1800 (1 Rx,4 Tx) @power level #5 Typical: 237mA DCS1800 (1 Rx,4 Tx) @power level #5 Typical: 237mA DCS1800 (3Rx, 2 Tx) @power level #0 Typical: 275mA EDGE GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 300mA DCS1800 (3Rx, 2 Tx) @power level #8 Typical: 300mA DCS1800 (1 Rx,4 Tx) @power level #8 Typical: 300mA DCS1800 (1 Rx,4 Tx) @power level #8 Typical: 300mA GSM 900 (3 Rx, 2 Tx) @power level #8 Typical: 230mA DCS1800 (3 Rx, 2 Tx) @power level #8 Typical: 230mA DCS1800 (3 Rx, 2 Tx) @power level #8 Typical: 230mA DCS1800 (3 Rx, 2 Tx) @power level #8 Typical: 230mA DCS1800 (3 Rx, 2 Tx) @power level #8 Typical: 300mA GSM 900 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 230mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 300mA DCS1800 (3 Rx, 2 Tx) @power level #3 Typical: 489mA DCS1800 (3 Rx, 2 Tx) @power level #3 Typical: 491mA DCS1800 (3 Rx, 2 Tx) @power level #3 Typical: 491mA DCS1800 (3 Rx, 2 Tx) @power level #3 Typical: 491mA DCS1800 (3 Rx, 2 Tx) @power level #3 Typical: 491mA	,	idic mode (a) B5_171_wii kivis 2 Typicai. Tomizi
(without UB connection) Idle mode @DRX=9 Typical: 17.5mA LTE Sleep/Idle mode Sleep mode Typical: 1.56mA LTE supply current Sleep mode Typical: 13.7mA (without USB connection) Idle mode Typical: 13.7mA GSM Talk GSM 900 @power level #5 Typical: 220mA DCS1800 @power level #5 Typical: 162mA UMTS Talk WCDMA B2 @Power 22dBm Typical: 524mA WCDMA B5 @Power 23.48dBm Typical: 480mA GPRS GSM 900 (1 Rx,4 Tx) @power level #5 Typical: 230mA DCS1800 (1 Rx,4 Tx) @power level #5 Typical: 370mA DCS1800 (3Rx, 2 Tx) @power level #6 Typical: 275mA EDGE GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 300mA DCS1800 (1 Rx,4 Tx) @power level #8 Typical: 300mA GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 320mA DCS1800 (3Rx, 2 Tx) @power level #8 Typical: 320mA DCS1800 (3 Rx, 2 Tx) @power level #8 Typical: 320mA DCS1800 (3Rx, 2 Tx) @power level #8 Typical: 320mA MCDMA B2 @power level #8 Typical: TBD WCDMA B5 @power level #8 Typical: TBD LTE-FDD B1 @power level #8 Typical: 348mA	•	Clean made @DDV=0 Typical: 1.11m A
LTE Sleep/Idle mode	* * *	
Sleep mode Typical: 1.56mA	,	Idle mode @DKX=9 Typical: 17.5mA
(without USB connection) Idle mode Typical: 13.7mA GSM Talk (@power level #5 Typical: 220mA) DCS1800 (@power level #5 Typical: 162mA) UMTS Talk (@Power 22dBm) Typical: 524mA WCDMA B2 (@Power 23.48dBm) Typical: 524mA WCDMA B5 (@Power level #5 Typical: 230mA) GSM 900 (1 Rx,4 Tx) (@power level #5 Typical: 230mA) DCS1800 (1 Rx,4 Tx) (@power level #5 Typical: 370mA) GSM 900 (3 Rx, 2 Tx) (@power level #5 Typical: 275mA) EDGE (@power level #8 Typical: 275mA) EDGE (@power level #8 Typical: 300mA) GSM 900 (1 Rx,4 Tx) (@power level #8 Typical: 300mA) DCS1800 (1 Rx,4 Tx) (@power level #8 Typical: 320mA) DCS1800 (3 Rx, 2 Tx) (@power level #8 Typical: 320mA) DCS1800 (3 Rx, 2 Tx) (@power level #8 Typical: 230mA) MCDMA B2 (@Power 24dBm Typical: TBD) WCDMA B5 (@Power 24dBm Typical: TBD) LTE-FDD B1 (@5 MHz 22.2dBm Typical: 334mA) (@5 MHz 22.3dBm Typical: 534mA) (@5 MHz 22.3dBm Typical: 577mA (@20 MHz 22.3dBm Typical: 626mA) (@5 MHz 22.3dBm Typical: 491mA) LTE-FDD B3 </td <td></td> <td></td>		
GSM Talk GSM 900	* * *	
GSM 900	,	Idle mode Typical: 13.7mA
DCS1800		
WCDMA B2 @Power 22.dBm Typical: 524mA WCDMA B5 @Power 23.48dBm Typical: 480mA GPRS GSM 900 (1 Rx,4 Tx)		
WCDMA B5 @Power 23.48dBm Typical: 524mA GPRS @Power 23.48dBm Typical: 480mA GSM 900 (1 Rx,4 Tx) @power level #5 Typical: 230mA DCS1800 (1 Rx,4 Tx) @power level #0 Typical: 195mA GSM 900 (3 Rx, 2 Tx) @power level #5 Typical: 370mA DCS1800 (3 Rx, 2 Tx) @power level #0 Typical: 275mA EDGE Bypical: 400mA GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 300mA GSM 900 (3 Rx, 2 Tx) @power level #2 Typical: 320mA DCS1800 (3 Rx, 2 Tx) @power level #2 Typical: 320mA HSDPA Data WCDMA B2 WCDMA B5 @Power 24dBm Typical: TBD LTE Data @5 MHz 22.2dBm Typical: 482mA LTE-FDD B1 @10 MHz 22.7dBm Typical: 534mA @20 MHz 22.38dBm Typical: 534mA LTE-FDD B2 @10 MHz 22.7dBm Typical: 577mA @20 MHz 22.38dBm Typical: 626mA @5 MHz 22.2dBm Typical: 479mA LTE-FDD B3 @10 MHz 22.7dBm Typical: 491mA		@power level #5 Typical: 162mA
### Compage 12 ### Compage 23 ### Compage 23 ### Compage 24 ### Compage 24 ### Compage 24 ### Compage 25 ### Compage 26 ### Compage 27 ### Co	UMTS Talk	
GPRS GSM 900 (1 Rx,4 Tx)	WCDMA B2	@Power 22dBm Typical: 524mA
GSM 900 (1 Rx,4 Tx)	WCDMA B5	@Power 23.48dBm Typical: 480mA
DCS1800 (1 Rx,4 Tx)	GPRS	
GSM 900 (3Rx, 2 Tx)	GSM 900 (1 Rx,4 Tx)	@power level #5 Typical: 230mA
DCS1800 (3Rx, 2 Tx) @power level #0 Typical: 275mA EDGE GSM 900 (1 Rx,4 Tx) @power level #8 Typical: 400mA DCS1800 (1 Rx,4 Tx) @power level #2 Typical: 300mA GSM 900 (3Rx, 2 Tx) @power level #8 Typical: 320mA HSDPA Data WCDMA B2 @Power 24dBm Typical: TBD WCDMA B5 @Power 24dBm Typical: TBD LTE Data @5 MHz 22.2dBm Typical: 482mA @10 MHz 22.7dBm Typical: 489mA @20 MHz 22.2dBm Typical: 534mA @5 MHz 22.2dBm Typical: 577mA @20 MHz 22.38dBm Typical: 626mA @5 MHz 22.2dBm Typical: 479mA LTE-FDD B3 MHz 22.2dBm Typical: 491mA	DCS1800 (1 Rx,4 Tx)	@power level #0 Typical: 195mA
### Company of the co	GSM 900 (3Rx, 2 Tx)	@power level #5 Typical: 370mA
GSM 900 (1 Rx,4 Tx)	DCS1800 (3Rx, 2 Tx)	@power level #0 Typical: 275mA
DCS1800 (1 Rx,4 Tx)	EDGE	
GSM 900 (3Rx, 2 Tx)	GSM 900 (1 Rx,4 Tx)	@power level #8 Typical: 400mA
DCS1800 (3Rx, 2 Tx)		
## WCDMA B2 ## WCDMA B5 ## WCDMA B2 ## WCMA B2 #	GSM 900 (3Rx, 2 Tx)	<u> </u>
WCDMA B2 @Power 24dBm Typical: TBD WCDMA B5 @Power 24dBm Typical: TBD LTE Data @5 MHz 22.2dBm Typical: 482mA LTE-FDD B1 @10 MHz 22.7dBm Typical: 489mA @20 MHz 22.38dBm Typical: 534mA LTE-FDD B2 @10 MHz 22.2dBm Typical: 589mA LTE-FDD B3 @5 MHz 22.2dBm Typical: 479mA @10 MHz 22.2dBm Typical: 479mA @10 MHz 22.7dBm Typical: 491mA		@power level #2 Typical: 230mA
WCDMA B5 @Power 24dBm Typical: TBD LTE Data @5 MHz 22.2dBm Typical: 482mA LTE-FDD B1 @10 MHz 22.7dBm Typical: 489mA @20 MHz 22.38dBm Typical: 534mA LTE-FDD B2 @10 MHz 22.7dBm Typical: 577mA @20 MHz 22.38dBm Typical: 626mA LTE-FDD B3 @5 MHz 22.2dBm Typical: 479mA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCDMA WCD		
LTE Data @5 MHz		<u> </u>
(a) 5 MHz 22.2dBm Typical: 482mA (a) 10 MHz 22.7dBm Typical: 489mA (a) 20 MHz 22.38dBm Typical: 534mA (a) 5 MHz 22.2dBm Typical: 589mA (a) 10 MHz 22.7dBm Typical: 577mA (a) 20 MHz 22.38dBm Typical: 626mA (a) 5 MHz 22.2dBm Typical: 479mA (a) 5 MHz 22.7dBm Typical: 491mA		@Power 24dBm Typical: TBD
LTE-FDD B1 @ 10 MHz	LTE Data	
@20 MHz 22.38dBm Typical: 534mA @5 MHz 22.2dBm Typical: 589mA LTE-FDD B2 @10 MHz 22.7dBm Typical: 577mA @20 MHz 22.38dBm Typical: 626mA @5 MHz 22.2dBm Typical: 479mA LTE-FDD B3 @10 MHz 22.7dBm Typical: 491mA	LTE EDD D1	
(a)5 MHz 22.2dBm Typical: 589mA (a)10 MHz 22.7dBm Typical: 577mA (a)20 MHz 22.38dBm Typical: 626mA (a)5 MHz 22.2dBm Typical: 479mA (a)10 MHz 22.7dBm Typical: 479mA (a)10 MHz 22.7dBm Typical: 491mA	LIE-FDD BI	\cup
LTE-FDD B2 @ 10 MHz 22.7dBm Typical: 577mA @ 20 MHz 22.38dBm Typical: 626mA @ 5 MHz 22.2dBm Typical: 479mA LTE-FDD B3 @ 10 MHz 22.7dBm Typical: 491mA		
@20 MHz 22.38dBm Typical: 626mA @5 MHz 22.2dBm Typical: 479mA LTE-FDD B3 @10 MHz 22.7dBm Typical: 491mA	LTE-FDD B2	\cup
LTE-FDD B3 @10 MHz 22.7dBm Typical: 491mA		<u> </u>
\cup		\bigcirc
(a)20 MHz 22 3XdRm Tynical: 538mA	LTE-FDD B3	\bigcirc
		@20 MHz 22.38dBm Typical: 538mA
@5 MHz 23.05dBm Typical: 519mA LTE-FDD B4 @10 MHz 23.04dBm Typical: 556mA	LTE EDD R4	\cup
@20 MHz 22.83dBm Typical: 600mA	LIL-IUU U4	\cup



LTE-FDD B5	TBD
LTE-FDD B7	 @5 MHz 22.64dBm Typical: 593mA @10 MHz 22.66dBm Typical: 611mA @20 MHz 24.5dBm Typical: 650mA
LTE-FDD B8	@5 MHz 22.2dBm Typical: 476mA@10 MHz 22.7dBm Typical: 481mA
LTE-FDD B12	@5 MHz22.69dBmTypical: 516mA@10 MHz22.9dBmTypical: 512mA
LTE-FDD B18	@5 MHz@10 MHz23.3dBmTypical: 477mATypical: 482mA
LTE-FDD B19	@5 MHz@10 MHz23.4dBmTypical: 412mATypical: 450mA
LTE-FDD B20	 @5 MHz @10 MHz @24dBm Typical: 526mA @20 MHz 23.9dBm Typical: 670mA
LTE-FDD B25	TBD
LTE-FDD B26	@5 MHz@10 MHz23.4dBmTypical: 433mATypical: 480mA
LTE-FDD B28	 @5 MHz @10 MHz @2.66dBm Typical: 700mA @20 MHz 24.5dBm Typical: 700mA

5.5 ESD Notes

Module is sensitive to ESD in the process of storage, transporting and assembling. Especially, Module is mounted on the users' mother board, The ESD components should be placed beside the connectors which human body might touch, such as SIM card holder, audio jacks, switches and keys, etc. The following table shows the Module ESD measurement performance without any external ESD component.

Table 35: The ESD performance measurement table (Temperature: 25°C, Humidity: 45%)

Part	Contact discharge	Air discharge
GND	+/-6K	+/-12K
VBAT	+/-5K	+/-10K
Antenna port	+/-5K	+/-10K
USB	+/-4K	+/-8K
UART	+/-4K	+/-8K
PCM	+/-4K	+/-8K
Other PADs	+/-3K	+/-6K



6 SMT Production Guide

6.1 Top and Bottom View of Module



Figure 33: Top and bottom view of Module



6.2 Label Information



Figure 34: Label Information

Table 36: The Description of Label Information

No.	Description
A	LOGO
В	No.1 Pin
C	Project Name
D	Product Code
E	Serial Number
F	International Mobile Equipment Identity
G	QR code

6.3 Typical SMT Reflow Profile

SIMCom provides a typical soldering profile. Therefore the soldering profile shown below is only a generic recommendation and should be adjusted to the specific application and manufacturing constraints.



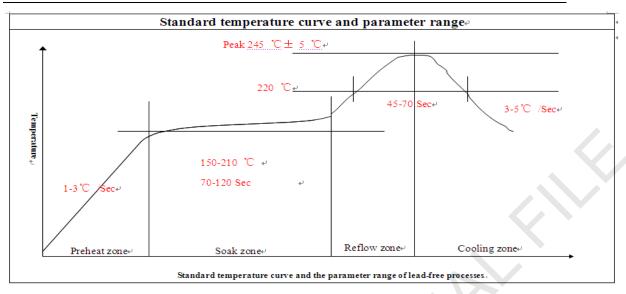


Figure 35: The ramp-soak-spike Reflow Profile of Module

Note: For more details about secondary SMT, please refer to the document [21].

6.4 Moisture Sensitivity Level (MSL)

Module is qualified to Moisture Sensitivity Level (MSL) 3 in accordance with JEDEC J-STD-033. If the prescribed time limit is exceeded, users should bake modules for 192 hours in drying equipment (<5% RH) at 40+5/-0°C, or 72 hours at 85+5/-5°C. Note that plastic tray is not heat-resistant, and only can be baked at 45° C.

Table 37: Moisture Sensitivity Level and Floor Life

Moisture Sensitivity Level	Floor Life (out of bag) at	factory ambient≤30°C/60% RH or as
(MSL)	stated	
1	Unlimited at	≦30°C/85% RH
2	1 year	
2a	4 weeks	
3	168 hours	
4	72 hours	
5	48 hours	
5a	24 hours	
6	Mandatory bake before use. A time limit specified on the labe	fter bake, it must be reflowed within the el.

NOTE: IPC / JEDEC J-STD-033 standard must be followed for production and storage.



6.5 Stencil Foil Design Recommendation

The recommended thickness of stencil foil is 0.13mm.



7 Packaging

Module module support tray packaging.

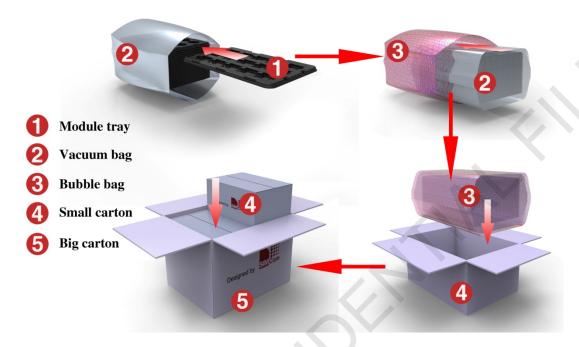


Figure 36: Packaging introduce

Module tray drawing:

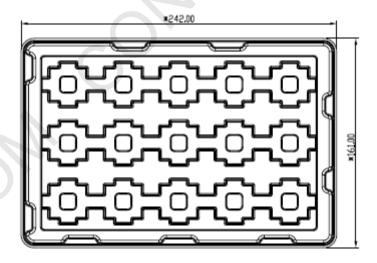


Figure 37: Module tray drawing introduce

Table 38: Tray size

Length (±3mm)	Width (±3mm)	Module number
242.0	161.0	15



Small carton drawing:

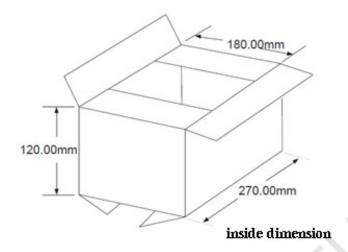


Figure 38: Small carton drawing introduce

Table 39: Small Carton size

Length (±10mm)	Width (±10mm)	Height (±10mm)	Module number
270	180	120	15*20=300

Big carton drawing:

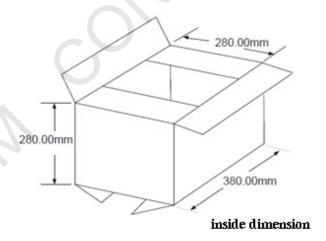


Figure 39: Big carton drawing introduce

Table 40: Big carton size

Length (±10mm)	Width (±10mm)	Height (±10mm)	Module number
380	280	280	300*4=1200



Appendix

A. Reference Design

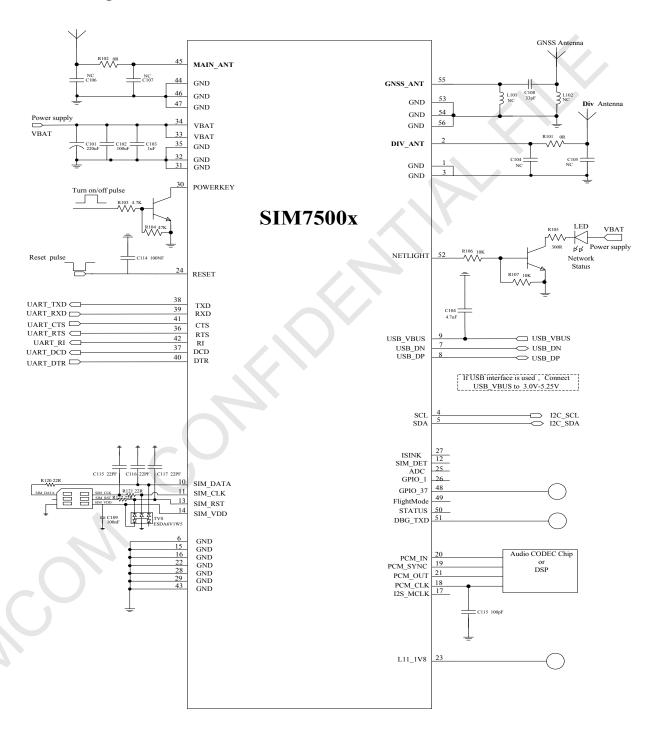


Figure 40: Reference design

Note: 1. The UART port suggest to be used by isolated circuit.

2. If use SIM7500E Module, C115 should use 220pF.

3.C115 must be mounted.



B. Coding Schemes and Maximum Net Data Rates over Air Interface

Table 41: Coding schemes and maximum net data rates over air interface

Slot class	DL slot number	UL slot number	Active slot number
1	1	1	2
2	2	1	3
3	2	2	3
4	3	1	4
5	2	2	4
<u>6</u> 7	3	3	4
8	4	1	5
9	3	2	5
10	4	2	5
11	4	3	5
12	4	4	5
GPRS coding scheme	Max data rata (4)	slots)	Modulation type
CS $1 = 9.05 \text{ kb/s} / \text{time slot}$	36.2 kb/s		GMSK
CS 2 = 13.4 kb/s / time slot	53.6 kb/s	53.6 kb/s	
CS 3 = 15.6 kb/s / time slot	62.4 kb/s		GMSK
CS 4 = 21.4 kb/s / time slot	85.6 kb/s		GMSK
EDGE coding scheme	Max data rata (4 slots)		Modulation type
MCS $1 = 8.8 \text{ kb/s/ time slot}$	35.2 kb/s		GMSK
MCS $2 = 11.2 \text{ kb/s/ time slot}$	44.8 kb/s		GMSK
MCS $3 = 14.8 \text{ kb/s/ time slot}$	59.2 kb/s		GMSK
MCS $4 = 17.6 \text{ kb/s/time slot}$	70.4 kb/s		GMSK
MCS $5 = 22.4 \text{ kb/s/ time slot}$	89.6 kb/s		8PSK
MCS $6 = 29.6 \text{ kb/s/ time slot}$	118.4 kb/s		8PSK
MCS $7 = 44.8 \text{ kb/s/time slot}$	179.2 kb/s		8PSK
MCS $8 = 54.4 \text{ kb/s/ time slot}$	217.6 kb/s		8PSK
MCS $9 = 59.2 \text{ kb/s/time slot}$	236.8 kb/s	236.8 kb/s	
HSDPA device category	Max data rate (pe	Max data rate (peak)	
Category 1	1.2Mbps	1.2Mbps	
Category 2	1.2Mbps		16QAM,QPSK
Category 3	1.8Mbps		16QAM,QPSK
Category 4	1.8Mbps	1.8Mbps	
Category 5	3.6Mbps		16QAM,QPSK
Category 6	3.6Mbps	3.6Mbps	
Category 7	7.2Mbps		16QAM,QPSK



A company of SIM Tech	Siliart M	achine Smart Decision
Category 8	7.2Mbps	16QAM,QPSK
Category 9	10.2Mbps	16QAM,QPSK
Category 10	14.4Mbps	16QAM,QPSK
Category 11	0.9Mbps	QPSK
Category 12	1.8Mbps	QPSK
Category 13	17.6Mbps	64QAM
Category 14	21.1Mbps	64QAM
Category 15	23.4Mbps	16QAM
Category 16	28Mbps	16QAM
Category 17	23.4Mbps	64QAM
Category 18	28Mbps	64QAM
Category 19	35.5Mbps	64QAM
Category 20	42Mbps	64QAM
Category 21	23.4Mbps	16QAM
Category 22	28Mbps	16QAM
Category 23	35.5Mbps	64QAM
Category 24	42.2Mbps	64QAM
HSUPA device category	Max data rate (peak)	Modulation type
Category 1	0.96Mbps	QPSK
Category 2	1.92Mbps	QPSK
Category 3	1.92Mbps	QPSK
Category 4	3.84Mbps	QPSK
Category 5	3.84Mbps	QPSK
Category 6	5.76Mbps	QPSK
LTE-FDD device category (Downlink)	Max data rate (peak)	Modulation type
Category 1	10Mbps	QPSK/16QAM/64QAM
Category 2	50Mbps	QPSK/16QAM/64QAM
Category 3	100Mbps	QPSK/16QAM/64QAM
Category 4	150Mbps	QPSK/16QAM/64QAM
LTE-FDD device category (Uplink)	Max data rate (peak)	Modulation type
Category 1	5Mbps	QPSK/16QAM
Category 2	25Mbps	QPSK/16QAM
Category 3	50Mbps	QPSK/16QAM
Category 4	50Mbps	QPSK/16QAM



C. Related Documents

Table 42: Related documents

SN	Title	Description
[1]	SIM7X00 Series_AT Command Manual_V1.xx	SIM7X00 Series_AT Command Manual
[2]	ITU-T Draft new recommendationV.25ter	Serial asynchronous automatic dialing and control
[3]	GSM 07.07	Digital cellular telecommunications (Phase 2+); AT command set for GSM Mobile Equipment (ME)
[4]	GSM 07.10	Support GSM 07.10 multiplexing protocol
[5]	GSM 07.05	Digital cellular telecommunications (Phase 2+); Use of Data Terminal Equipment – Data Circuit terminating Equipment (DTE – DCE) interface for Short Message Service (SMS) and Cell Broadcast Service (CBS)
[6]	GSM 11.14	Digital cellular telecommunications system (Phase 2+); Specification of the SIM Application Toolkit for the Subscriber Identity Module – Mobile Equipment (SIM – ME) interface
[7]	GSM 11.11	Digital cellular telecommunications system (Phase 2+); Specification of the Subscriber Identity Module – Mobile Equipment (SIM – ME) interface
[8]	GSM 03.38	Digital cellular telecommunications system (Phase 2+); Alphabets and language-specific information
[9]	GSM 11.10	Digital cellular telecommunications system (Phase 2); Mobile Station (MS) conformance specification; Part 1: Conformance specification
[10]	3GPP TS 51.010-1	Digital cellular telecommunications system (Release 5); Mobile Station (MS) conformance specification
[11]	3GPP TS 34.124	Electromagnetic Compatibility (EMC) for mobile terminals and ancillary equipment.
[12]	3GPP TS 34.121	Electromagnetic Compatibility (EMC) for mobile terminals and ancillary equipment.
[13]	3GPP TS 34.123-1	Technical Specification Group Radio Access Network; Terminal conformance specification; Radio transmission and reception (FDD)
[14]	3GPP TS 34.123-3	User Equipment (UE) conformance specification; Part 3: Abstract Test Suites.
[15]	EN 301 908-02 V2.2.1	Electromagnetic compatibility and Radio spectrum Matters (ERM); Base Stations (BS) and User Equipment (UE) for IMT-2000. Third Generation cellular networks; Part 2: Harmonized EN for IMT-2000, CDMA Direct Spread (UTRA FDD) (UE) covering essential requirements of article 3.2 of the R&TTE Directive
[16]	EN 301 489-24 V1.2.1	Electromagnetic compatibility and Radio Spectrum Matters (ERM); Electromagnetic Compatibility (EMC) standard for radio equipment and services; Part 24: Specific conditions for IMT-2000 CDMA Direct Spread (UTRA) for Mobile and portable (UE) radio and ancillary equipment
[17]	IEC/EN60950-1(2001)	Safety of information technology equipment (2000)
[18]	3GPP TS 51.010-1	Digital cellular telecommunications system (Release 5);



		Mobile Station (MS) conformance specification
[19]	GCF-CC V3.23.1	Global Certification Forum - Certification Criteria
[20]	2002/95/EC	Directive of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS)
[21]	Module secondary-SMT-UGD-V1.xx	Module secondary SMT Guidelines
[22]	SIM7X00	SIM7X00 Series_UART_Application Note
	Series_UART_Application	
	Note_V1.xx	
	SIM7X00 Series_USB	an reveal and the state of the
[23]	AUDIO_Application	SIM7X00 Series_USB AUDIO_Application Note
	Note_V1.xx	
[24]	Antenna design guidelines for diversity receiver system	Antenna design guidelines for diversity receiver system
[25]	SIM7X00 Series_Sleep Mode_ Application Note_V1.xx	SIM7X00 Series_Sleep Mode_Application Note



D. Terms and Abbreviations

Table 43: Terms and Abbreviations

Abbreviation	Description
ADC	Analog-to-Digital Converter
ARP	Antenna Reference Point
BER	Bit Error Rate
BTS	Base Transceiver Station
CS	Coding Scheme
CSD	Circuit Switched Data
CTS	Clear to Send
DAC	Digital-to-Analog Converter
DRX	Discontinuous Reception
DSP	Digital Signal Processor
DTE	Data Terminal Equipment (typically computer, terminal, printer)
DTR	Data Terminal Ready
DTX	Discontinuous Transmission
EFR	Enhanced Full Rate
EGSM	Enhanced GSM
EMC	Electromagnetic Compatibility
ESD	Electrostatic Discharge
ETS	European Telecommunication Standard
EVDO	Evolution Data Only
FCC	Federal Communications Commission (U.S.)
FD	SIM fix dialing phonebook
FDMA	Frequency Division Multiple Access
FR	Full Rate
GMSK	Gaussian Minimum Shift Keying
GPRS	General Packet Radio Service
GSM	Global Standard for Mobile Communications
GNSS	Global Navigation Satellite System
HR	Half Rate
HSPA	High Speed Packet Access
I2C	Inter-Integrated Circuit
IMEI	International Mobile Equipment Identity
LTE	Long Term Evolution
MO	Mobile Originated
MS	Mobile Station (GSM engine), also referred to as TE
MT	Mobile Terminated
PAP	Password Authentication Protocol
PBCCH	Packet Switched Broadcast Control Channel
PCB	Printed Circuit Board
PCS	Personal Communication System, also referred to as GSM 1900
RF	Radio Frequency
RMS	Root Mean Square (value)



	Smart Machine Smart Decision
RTC	Real Time Clock
SIM	Subscriber Identification Module
SMS	Short Message Service
SPI	serial peripheral interface
SMPS	Switched-mode power supply
TDMA	Time Division Multiple Access
TE	Terminal Equipment, also referred to as DTE
TX	Transmit Direction
UART	Universal Asynchronous Receiver & Transmitter
VSWR	Voltage Standing Wave Ratio
SM	SIM phonebook
NC	Not connect
EDGE	Enhanced data rates for GSM evolution
HSDPA	High Speed Downlink Packet Access
HSUPA	High Speed Uplink Packet Access
ZIF	Zero intermediate frequency
WCDMA	Wideband Code Division Multiple Access
VCTCXO	Voltage control temperature-compensated crystal oscillator
SIM	Universal subscriber identity module
UMTS	Universal mobile telecommunications system
UART	Universal asynchronous receiver transmitter



E. Safety Caution

Table 44: Safety caution

Marks	Requirements
•	When in a hospital or other health care facility, observe the restrictions about the use of mobiles. Switch the cellular terminal or mobile off, medical equipment may be sensitive and not operate normally due to RF energy interference.
X	Switch off the cellular terminal or mobile before boarding an aircraft. Make sure it is switched off. The operation of wireless appliances in an aircraft is forbidden to prevent interference with communication systems. Forgeting to think much of these instructions may impact the flight safety or offend local legal action, or both.
	Do not operate the cellular terminal or mobile in the presence of flammable gases or fumes. Switch off the cellular terminal when you are near petrol stations, fuel depots, chemical plants or where blasting operations are in progress. Operation of any electrical equipment in potentially explosive atmospheres can constitute a safety hazard.
	Your cellular terminal or mobile receives and transmits radio frequency energy while switched on. RF interference can occur if it is used close to TV sets, radios, computers or other electric equipment.
	Road safety comes first! Do not use a hand-held cellular terminal or mobile when driving a vehicle, unless it is securely mounted in a holder for hands free operation. Before making a call with a hand-held terminal or mobile, park the vehicle.
sos	GSM cellular terminals or mobiles operate over radio frequency signals and cellular networks and cannot be guaranteed to connect in all conditions, especially with a mobile fee or an invalid SIM card. While you are in this condition and need emergent help, please remember to use emergency calls. In order to make or receive calls, the cellular terminal or mobile must be switched on and in a service area with adequate cellular signal strength. Some networks do not allow for emergency call if certain network services or phone features are in use (e.g., lock functions, fixed dialing etc.) You may have to
MO	features are in use (e.g. lock functions, fixed dialing etc.). You may have to deactivate those features before you can make an emergency call. Also, some networks require that a valid SIM card be properly inserted in the cellular terminal or mobile.



Contact us:

Shanghai SIMCom Wireless Solutions Ltd.

Add: SIM Technology Building, No.633, Jinzhong Road, Changning District, Shanghai P.R. China

200335

Tel: +86 21 3235 3300 Fax: +86 21 3235 3020

URL: www.simcomm2m.com